

isc N-Channel MOSFET Transistor**IRF250****DESCRIPTION**

- Drain Current $-I_D=30A@ T_C=25^{\circ}C$
- Drain Source Voltage-
: $V_{DSS}= 200V(\text{Min})$
- Static Drain-Source On-Resistance
: $R_{DS(on)}=0.085 \Omega (\text{Max})$
- Nanosecond Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

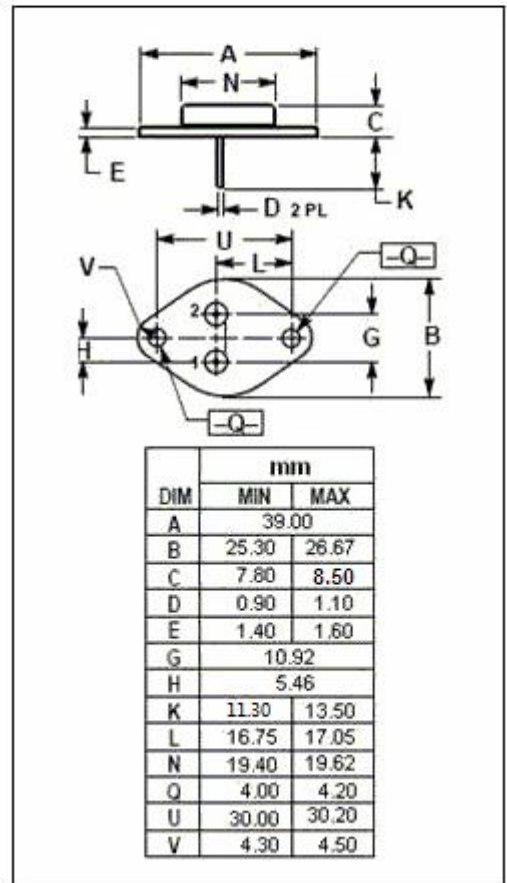
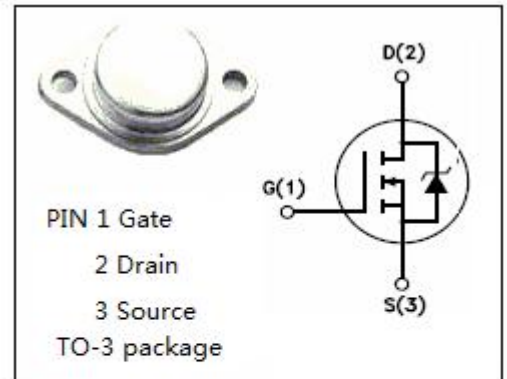
- Switching power supplies
- Switching converters, motor driver, relay driver

ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	200	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-continuous@ $T_C=25^{\circ}C$	30	A
P_{tot}	Total Dissipation@ $T_C=25^{\circ}C$	150	W
T_j	Max. Operating Junction Temperature	150	$^{\circ}C$
T_{stg}	Storage Temperature Range	-55~150	$^{\circ}C$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	0.83	$^{\circ}C/W$
$R_{th j-a}$	Thermal Resistance, Junction to Ambient	30	$^{\circ}C/W$



isc N-Channel MOSFET Transistor**IRF250****• ELECTRICAL CHARACTERISTICS (T_C=25°C)**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D =250μA	200			V
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250μA	2		4	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D =16A			0.085	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} =±20V; V _{DS} =0			± 100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =200V; V _{GS} =0			250	uA
V _{SD}	Diode Forward Voltage	I _S =30A; V _{GS} =0			2.0	V
C _{iss}	Input Capacitance	V _{DS} =25V; V _{GS} =0V; f _T =1MHz		2000	3000	pF
C _{rss}	Reverse Transfer Capacitance			300	500	
C _{oss}	Output Capacitance			800	1200	
t _r	Rise Time	I _D =16A; V _{DD} =95V; R _L =4.7 Ω			100	ns
t _{d(on)}	Turn-on Delay Time				35	
t _f	Fall Time				100	
t _{d(off)}	Turn-off Delay Time				125	

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